

# **PBHV9560ZX Datasheet**

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DiGi Electronics Part Number PBHV9560ZX-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number PBHV9560ZX

Description TRANS PNP 600V 0.5A SOT223

**Detailed Description** Bipolar (BJT) Transistor PNP 600 V 500 mA 38MHz 6

50 mW Surface Mount SOT-223



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# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
PBHV9560ZX	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
600 V	250mV @ 5mA, 50mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA	70 @ 50mA, 10V
Power - Max:	Frequency - Transition:
650 mW	38MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q100	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223
Base Product Number:	
PBHV9560	

# **Environmental & Export classification**

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

## 1. General description

PNP high-voltage low  $V_{CEsat}$  transistor in a medium power SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBHV8560Z

#### 2. Features and benefits

- High voltage
- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub>
- High collector current gain h<sub>FE</sub> at high I<sub>C</sub>

# 3. Applications

- · Electronic ballast for fluorescent lighting
- LED driver for LED chain module
- LCD backlighting
- HID front lighting
- · Hook switch for wired telecom
- Switch Mode Power Supply (SMPS)

#### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CESM</sub>	collector-emitter peak voltage	V <sub>BE</sub> = 0 V	-	-	-600	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-600	V
I <sub>C</sub>	collector current		-	-	-0.5	А
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -10 V; $I_{C}$ = -50 mA; $T_{amb}$ = 25 °C	70	130	-	

# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	C
2	С	collector		в
3	Е	emitter		
4	С	collector	1 2 3	Ė
			SC-73 (SOT223)	sym028



600 V, 0.5 A PNP high-voltage low VCEsat transistor

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package	ckage						
	Name	Description	Version					
PBHV9560Z		plastic, surface-mounted package with increased heatsink; 4 leads; 2.3 mm pitch; 6.5 mm x 3.5 mm x 1.65 mm body	SOT223					

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PBHV9560Z	HV956Z

# 8. Limiting values

#### Table 5. Limiting values

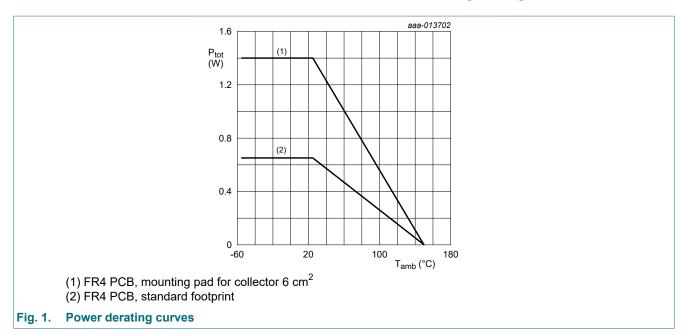
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-600	V
$V_{CEO}$	collector-emitter voltage	open base		-	-600	V
V <sub>CESM</sub>	collector-emitter peak voltage	V <sub>BE</sub> = 0 V		-	-600	V
$V_{EBO}$	emitter-base voltage	open collector		-	-6	V
I <sub>C</sub>	collector current			-	-0.5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	0.65	W
			[2]	-	1.4	W
T <sub>j</sub>	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

#### 600 V, 0.5 A PNP high-voltage low VCEsat transistor

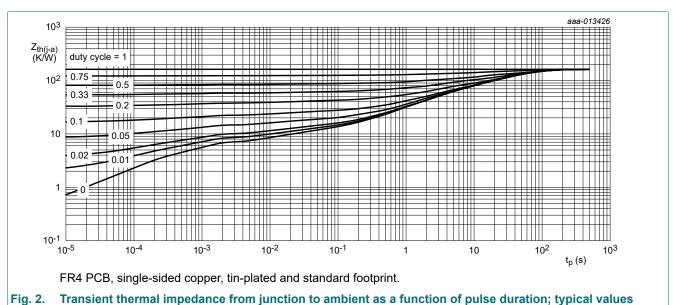


#### 9. Thermal characteristics

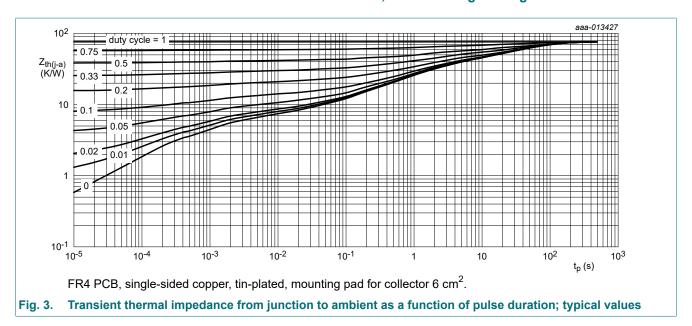
**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from	in free air	[1]	-	-	190	K/W
	junction to ambient		[2]	-	-	89	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	20	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.



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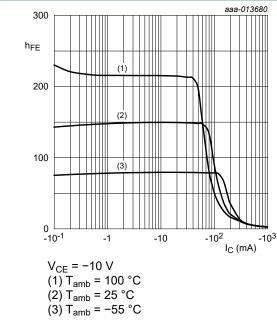


### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -400 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current	V <sub>CB</sub> = -400 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-10	μA
I <sub>CES</sub>	collector-emitter cut-off current	V <sub>CE</sub> = -400 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -10 V; I <sub>C</sub> = -50 mA; T <sub>amb</sub> = 25 °C	70	130	-	
		$V_{CE}$ = -10 V; $I_{C}$ = -100 mA; pulsed; $t_{p} \le$ 300 μs; $δ \le 0.02$ ; $T_{amb}$ = 25 °C	50	90	-	
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = -50 mA; I <sub>B</sub> = -5 mA; T <sub>amb</sub> = 25 °C	-	-150	-250	mV
	saturation voltage	$I_C$ = -100 mA; $I_B$ = -20 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-140	-250	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = -50 mA; $I_B$ = -5 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-	-900	mV
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -10 V; I <sub>C</sub> = -30 mA; f = 100 MHz	-	38	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -20 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$	-	12	-	pF
C <sub>e</sub>	emitter capacitance	$V_{EB}$ = -0.5 V; $I_{C}$ = 0 A; $i_{c}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C	-	390	-	pF

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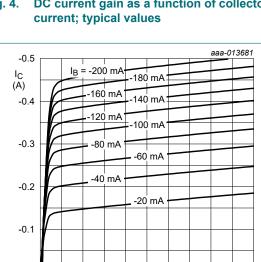


$$V_{CE} = -10 \text{ V}$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. DC current gain as a function of collector current; typical values



 $T_{amb}$  = 25 °C

-1

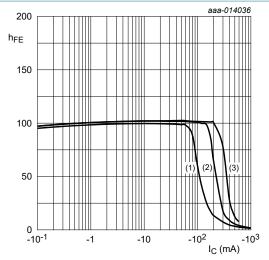
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Fig. 6. Collector current as a function of collectoremitter voltage; typical values

-2

-3

-4 V<sub>CE</sub> (V)

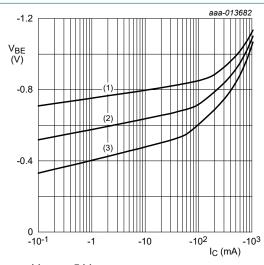


 $h_{FE} = f_{(IC)}$   $T_{amb} = 25 \,^{\circ}C$ (1)  $V_{CE} = -10 \,^{\circ}V$ 

$$(1) V_{CE} = -10 V_{CE}$$

(2) 
$$V_{CE} = -25 \text{ V}$$
  
(3)  $V_{CE} = -50 \text{ V}$ 

DC current gain as a function of collector Fig. 5. current; typical values



 $V_{CE} = -5 V$ 

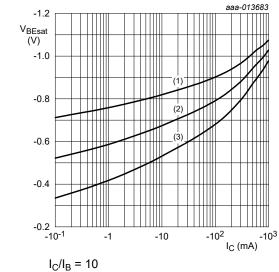
$$(1) T_{amb} = -55 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 7. Base-emitter voltage as a function of collector current; typical values

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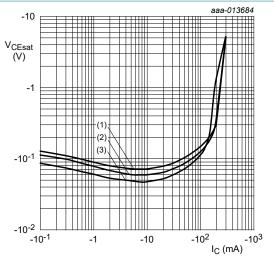
$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = -55 \,^{\circ}\text{C}$$
  
(2)  $T_{amb} = 25 \,^{\circ}\text{C}$   
(3)  $T_{amb} = 100 \,^{\circ}\text{C}$ 

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$





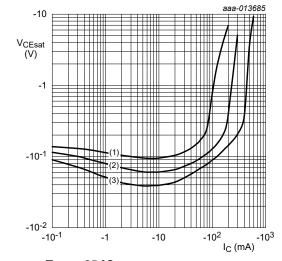
$$I_C/I_B = 5$$

(1) 
$$T_{amb} = 100 \text{ °C}$$
  
(2)  $T_{amb} = 25 \text{ °C}$   
(3)  $T_{amb} = -55 \text{ °C}$ 

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Collector-emitter saturation voltage as a function of collector current; typical values



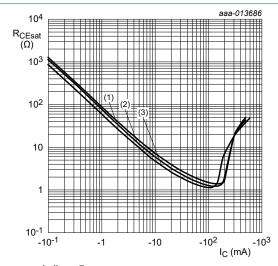
$$T_{amb}$$
 = 25 °C

(1) 
$$I_C/I_B = 10.0$$
  
(2)  $I_C/I_B = 5.0$ 

(2) 
$$I_C/I_B = 5.0$$

$$(3) I_{\rm C}/I_{\rm B} = 2.5$$

Fig. 10. Collector-emitter saturation voltage as a function of collector current; typical values



$$I_C/I_B = 5$$

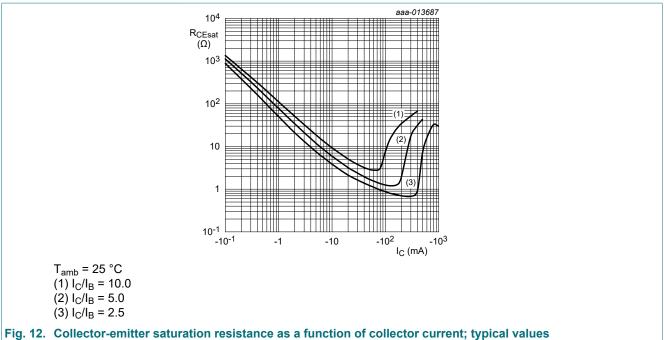
$$(1) T_{amb} = 100 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = -55 °C$$

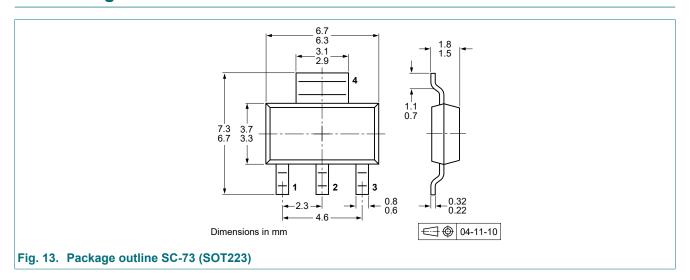
Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

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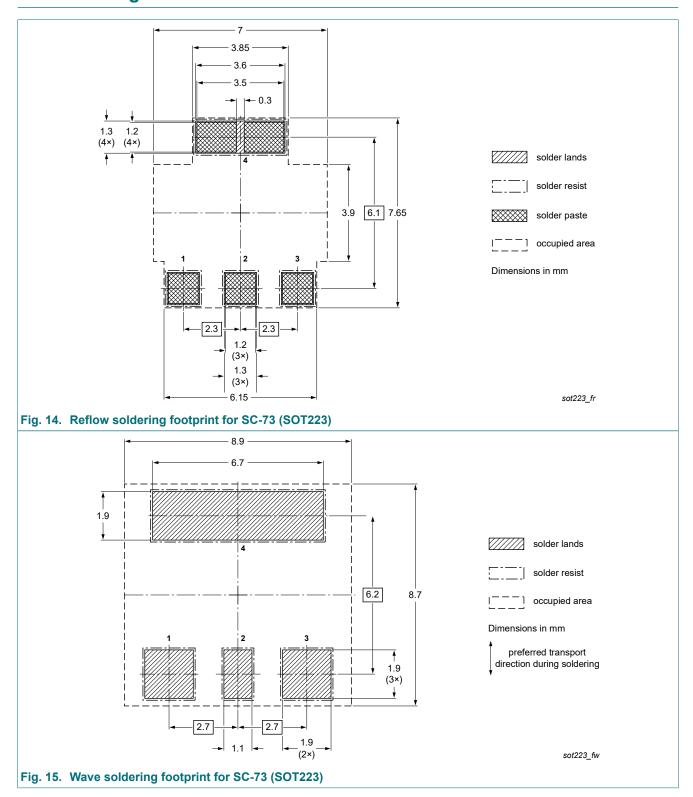
#### Tig. 12. Concettor-entitler saturation resistance as a function of concettor current, typical value

# 11. Package outline



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# 12. Soldering



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# 13. Revision history

#### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBHV9560Z v.2	20241008	Product data sheet	-	PBHV9560Z v.1			
Modifications:		<ul> <li>Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s).</li> </ul>					
PBHV9560Z v.1	20140812	Product data sheet	-	-			

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### 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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